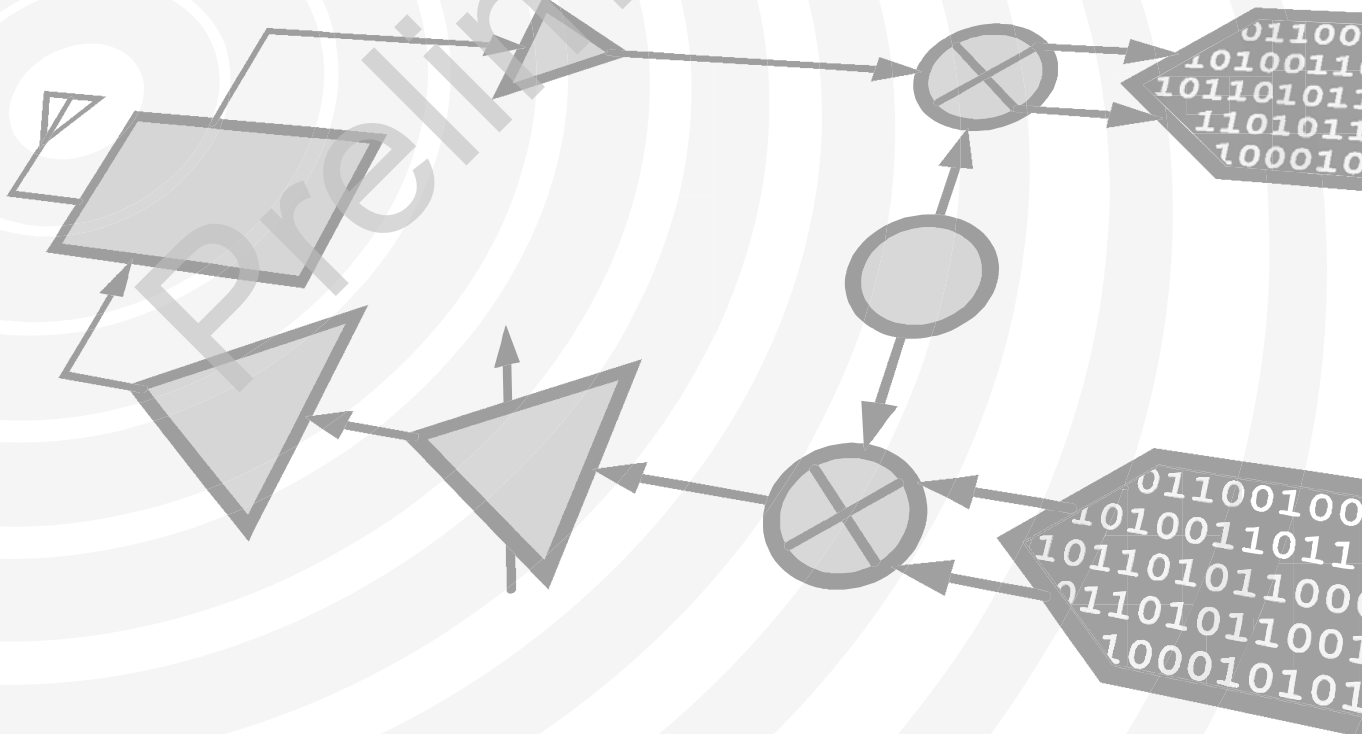


Analog Devices Welcomes Hittite Microwave Corporation



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Preliminary

GaAs MMIC SP8T NON-REFLECTIVE POSITIVE CONTROL SWITCH, DC* - 8 GHz

Typical Applications

This switch is suitable for usage in DC - 8.0 GHz

50-Ohm or 75-Ohm systems:

- Broadband
- Fiber Optics
- Switched Filter Banks
- Wireless below 8 GHz

Features

Broadband Performance: DC - 8 GHz

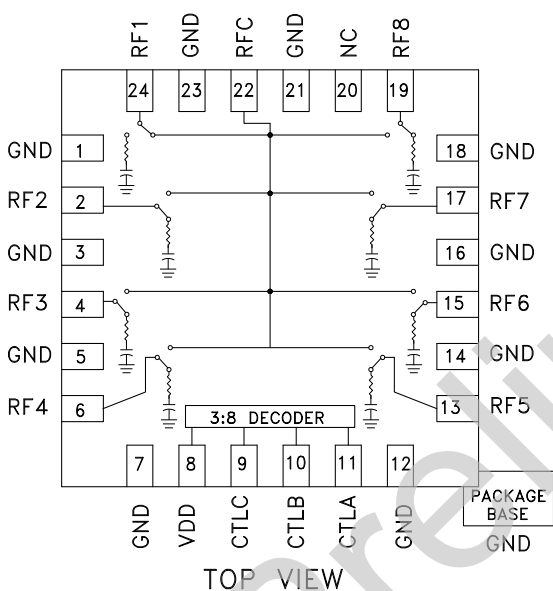
High Isolation: >30 dB@ 6 GHz

Low Insertion Loss: 2.5 dB@ 6 GHz

Integrated Positive Supply 3:8 TTL Decoder

4x4 mm SMT Package

Functional Diagram



General Description

The HMC321ALP4 & HMC321ALP4E are broadband non-reflective GaAs MESFET SP8T switches in low cost leadless surface mount packages. Covering DC to 8 GHz, this switch offers high isolation and low insertion loss. This switch also includes an on board binary decoder circuit which reduces the required logic control lines to three. The switch operates using a positive control voltage of 0/+5 volts, and requires a fixed bias of +5v. This switch is suitable for usage in 50-Ohm or 75-Ohm systems.

* DC blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6, 7, 8. Their value will determine the lowest transmission frequency.

Electrical Specifications, $T_A = +25^\circ \text{C}$, With 0/+5V Control, 50 Ohm System

Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 2.0 GHz		2.3	2.7	dB
	DC - 4.0 GHz		2.5	2.9	dB
	DC - 8.0 GHz		2.7	3.1	dB
Isolation	DC - 2.0 GHz	35	40		dB
	DC - 4.0 GHz	30	35		dB
	DC - 6.0 GHz	25	30		dB
	DC - 8.0 GHz	20	25		dB
Return Loss	"On State"	DC - 4.0 GHz	8	12	dB
		DC - 8.0 GHz	7	10	dB
Return Loss (RF1 - RF8)	"Off State"	2.0 - 8.0 GHz	7	12	dB
Input Power for 1 dB Compression	0.5 - 8.0 GHz	19	23		dBm
Input Third Order Intercept (Two-tone Input Power = +7 dBm Each Tone, 1 MHz Spacing)	0.5 - 8.0 GHz	33	40		dBm
Switching Characteristics	DC - 8.0 GHz	tRISE, tFALL (10/90% RF)	50		ns
		tON, tOFF (50% CTL to 10/90% RF)	150		ns

HMC321ALP4 / 321ALP4E

GaAs MMIC SP8T NON-REFLECTIVE POSITIVE CONTROL SWITCH, DC* - 8 GHz

Absolute Maximum Ratings

Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A, B, & C)	-0.5V to Vdd +1.0 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5V	+26 dBm
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Truth Table

Control Input			Signal Path State
A	B	C	RFCOM to:
Low	Low	Low	RF1
High	Low	Low	RF2
Low	High	Low	RF3
High	High	Low	RF4
Low	Low	High	RF5
High	Low	High	RF6
Low	High	High	RF7
High	High	High	RF8

Note:

DC blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6, 7, 8. Their value will determine the lowest transmission frequency.

Outline Drawing

